

**Product data sheet** 

# 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Low threshold voltage
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

# 3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Quick reference data

| Symbol                 | Parameter                        | Conditions   |     | Min | Тур | Max | Unit |
|------------------------|----------------------------------|--|-----|-----|-----|-----|------|
| V <sub>DS</sub>        | drain-source voltage             | T <sub>j</sub> = 25 °C   |     | -   | -   | 30  | V    |
| V <sub>GS</sub>        | gate-source voltage              |  |     | -12 | -   | 12  | V    |
| I <sub>D</sub>         | drain current                    | V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s         | [1] | -   | -   | 1   | Α    |
| Static characteristics |                                  |  |     |     |     |     |      |
| R <sub>DSon</sub>      | drain-source on-state resistance | $V_{GS} = 4.5 \text{ V}; I_D = 0.9 \text{ A}; T_j = 25 \text{ °C}$ |     | -   | 212 | 254 | mΩ   |

<sup>[1]</sup> Device mounted on an FR4 Printed Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



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# 5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline    | Graphic symbol |
|-----|--------|-------------|-----------------------|----------------|
| 1   | G      | gate        | □ 3                   | D<br>I         |
| 2   | S      | source      |                       |                |
| 3   | D      | drain       | 1 2<br>SC-70 (SOT323) | G S 017aaa255  |

# 6. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |  |  |  |
|-------------|---------|--|---------|--|--|--|
|             | Name    | Description                              | Version |  |  |  |
| PMF250XNE   | SC-70   | plastic surface-mounted package; 3 leads | SOT323  |  |  |  |

# 7. Marking

Table 4. Marking codes

| Type number | Marking code [1] |
|-------------|------------------|
| PMF250XNE   | Z%W              |

[1] % = placeholder for manufacturing site code

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# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions   |     | Min | Max | Unit |
|------------------|-------------------------|--|-----|-----|-----|------|
| V <sub>DS</sub>  | drain-source voltage    | T <sub>j</sub> = 25 °C   |     | -   | 30  | V    |
| $V_{GS}$         | gate-source voltage     |  |     | -12 | 12  | V    |
| I <sub>D</sub>   | drain current           | $V_{GS} = 4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$ | [1] | -   | 1   | Α    |
|                  |                         | V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C                    | [1] | -   | 0.9 | Α    |
|                  |                         | V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C                   | [1] | -   | 0.5 | Α    |
| I <sub>DM</sub>  | peak drain current      | $T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \mu s$                  |     | -   | 4   | Α    |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = 25 °C   | [2] | -   | 275 | mW   |
|                  |                         |  | [1] | -   | 342 | mW   |
|                  |                         | T <sub>sp</sub> = 25 °C  |     | -   | 1.1 | W    |
| Tj               | junction temperature    |  |     | -55 | 150 | °C   |
| T <sub>amb</sub> | ambient temperature     |  |     | -55 | 150 | °C   |
| T <sub>stg</sub> | storage temperature     |  |     | -65 | 150 | °C   |
| Source-drain     | n diode                 |  |     | '   |     |      |
| I <sub>S</sub>   | source current          | T <sub>amb</sub> = 25 °C   | [1] | -   | 0.3 | Α    |

<sup>[1]</sup> Device mounted on an FR4 Printed Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

#### **30V N-channel Trench MOSFET**

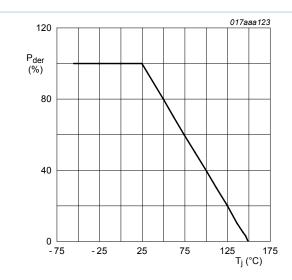


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

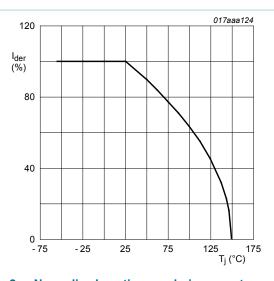


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

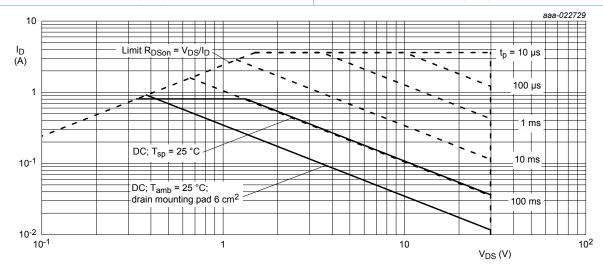


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

### 9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol               | Parameter                | Conditions  |     | Min | Тур | Max | Unit |
|----------------------|--------------------------|-------------|-----|-----|-----|-----|------|
| R <sub>th(j-a)</sub> | thermal resistance       | in free air | [1] | -   | 397 | 457 | K/W  |
|                      | from junction to ambient |             | [2] | -   | 318 | 366 | K/W  |
|                      |                          | t ≤ 5 s     | [2] | -   | 256 | 294 | K/W  |

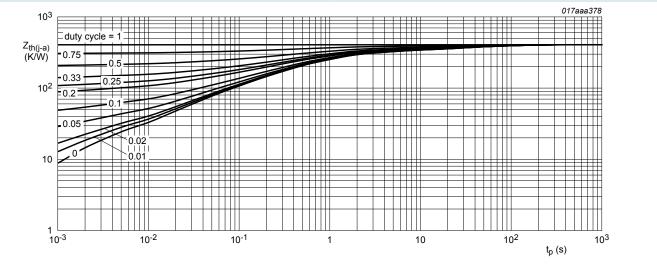
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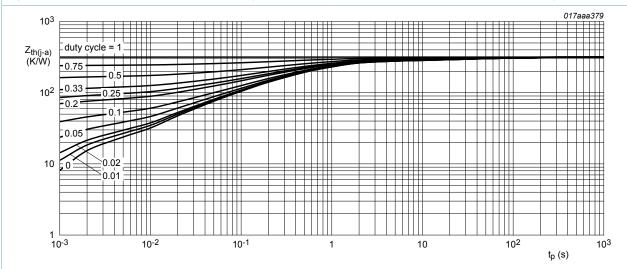
| Symbol                | Parameter  | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|------------|-----|-----|-----|------|
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |            | -   | 102 | 117 | K/W  |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 6 cm<sup>2</sup>

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

**30V N-channel Trench MOSFET** 

# 10. Characteristics

#### Table 7. Characteristics

| Symbol               | Parameter                      | Conditions   | Min  | Тур  | Max  | Unit |
|----------------------|--------------------------------|--|------|------|------|------|
| Static chara         | acteristics                    |  |      |      |      |      |
| V <sub>(BR)DSS</sub> | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$                             | 30   | -    | -    | V    |
| $V_{GSth}$           | gate-source threshold voltage  | $I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$                  | 0.75 | 1    | 1.25 | V    |
| I <sub>DSS</sub>     | drain leakage current          | V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C    | -    | -    | 1    | μA   |
| I <sub>GSS</sub>     | gate leakage current           | V <sub>GS</sub> = 12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C    | -    | -    | 10   | μA   |
|                      |                                | V <sub>GS</sub> = -12 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C   | -    | -    | -10  | μA   |
|                      |                                | V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C   | -    | -    | 5    | μA   |
|                      |                                | V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C  | -    | -    | -5   | μA   |
| R <sub>DSon</sub>    | drain-source on-state          | $V_{GS}$ = 4.5 V; $I_D$ = 0.9 A; $T_j$ = 25 °C                           | -    | 212  | 254  | mΩ   |
| resistance           | resistance                     | V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 0.9 A; T <sub>j</sub> = 150 °C | -    | 346  | 416  | mΩ   |
|                      |                                | V <sub>GS</sub> = 2.5 V; I <sub>D</sub> = 0.8 A; T <sub>j</sub> = 25 °C  | -    | 269  | 321  | mΩ   |
| 9 <sub>fs</sub>      | forward transconductance       | $V_{DS}$ = 10 V; $I_D$ = 0.9 A; $T_j$ = 25 °C                            | -    | 3.5  | -    | S    |
| Dynamic ch           | naracteristics                 |  | l    |      |      |      |
| Q <sub>G(tot)</sub>  | total gate charge              | $V_{DS}$ = 15 V; $I_D$ = 0.9 A; $V_{GS}$ = 4.5 V;                        | -    | 1.05 | 1.65 | nC   |
| $Q_{GS}$             | gate-source charge             | T <sub>j</sub> = 25 °C   | -    | 0.15 | -    | nC   |
| $Q_{GD}$             | gate-drain charge              |  | -    | 0.27 | -    | nC   |
| C <sub>iss</sub>     | input capacitance              | V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;                | -    | 81   | -    | pF   |
| C <sub>oss</sub>     | output capacitance             | T <sub>j</sub> = 25 °C   | -    | 13   | -    | pF   |
| C <sub>rss</sub>     | reverse transfer capacitance   |  | -    | 8.5  | -    | pF   |
| t <sub>d(on)</sub>   | turn-on delay time             | V <sub>DS</sub> = 15 V; I <sub>D</sub> = 0.9 A; V <sub>GS</sub> = 4.5 V; | -    | 7    | -    | ns   |
| t <sub>r</sub>       | rise time                      | $R_{G(ext)} = 6 \Omega$ ; $T_j = 25 °C$                                  | -    | 14   | -    | ns   |
| t <sub>d(off)</sub>  | turn-off delay time            |  | -    | 17   | -    | ns   |
| t <sub>f</sub>       | fall time                      |  | -    | 6    | -    | ns   |
| Source-dra           | in diode                       |  | I    | -    | -    |      |
| $V_{SD}$             | source-drain voltage           | I <sub>S</sub> = 0.3 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C    | -    | 0.7  | 1.2  | V    |

10<sup>-2</sup>

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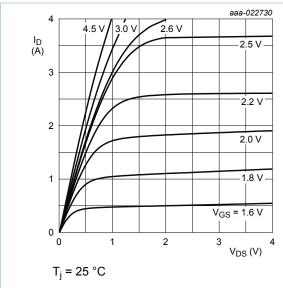


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

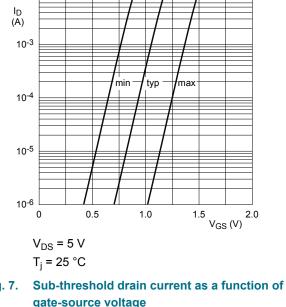
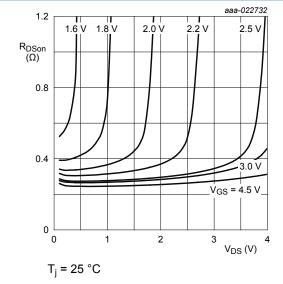


Fig. 7. gate-source voltage



Drain-source on-state resistance as a function Fig. 8. of drain current; typical values

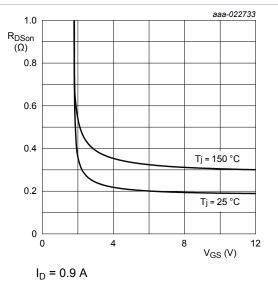


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

#### **30V N-channel Trench MOSFET**

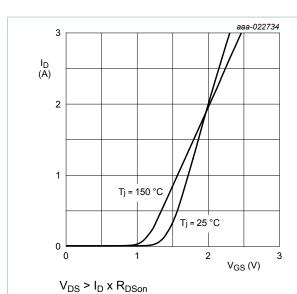


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

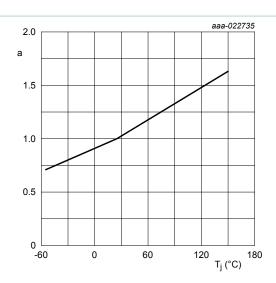


Fig. 11. Normalized drain-source on-state resistance as a function of ambient temperature; typical values

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

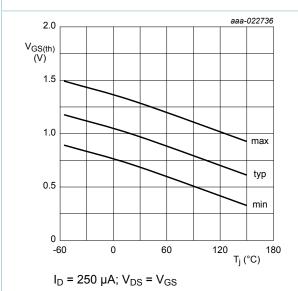


Fig. 12. Gate-source threshold voltage as a function of ambient temperature

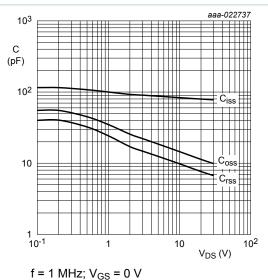


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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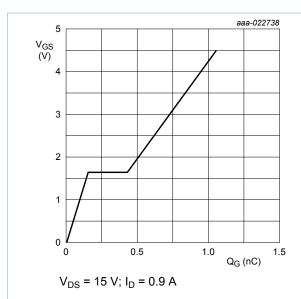


Fig. 14. Gate-source voltage as a function of gate charge; typical values

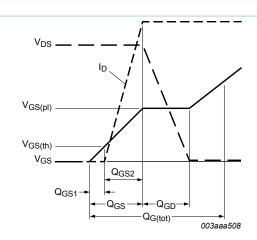


Fig. 15. Gate charge waveform definitions

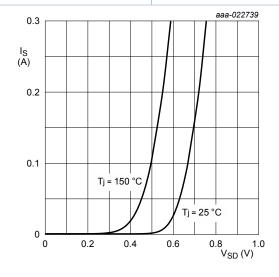
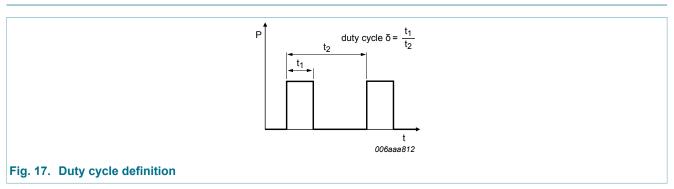


Fig. 16. Source current as a function of source-drain voltage; typical values

## 11. Test information

 $V_{GS} = 0 V$ 

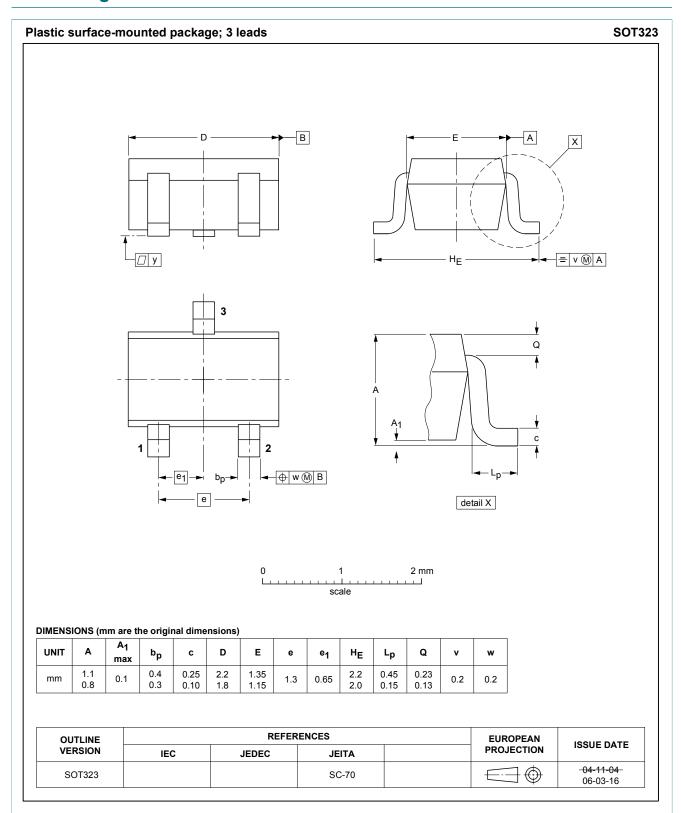


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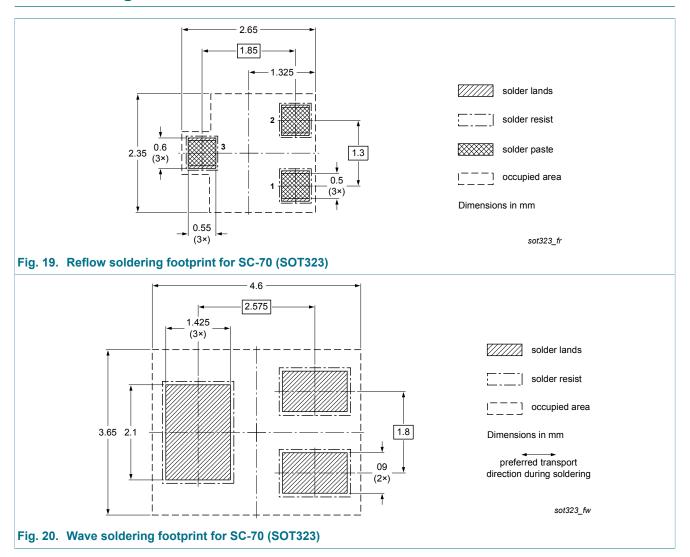
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# 12. Package outline



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# 13. Soldering



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# 14. Revision history

### Table 8. Revision history

| Data sheet ID | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PMF250XNE v.1 | 20160428     | Product data sheet | -             | -          |

#### 30V N-channel Trench MOSFET

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|--------------------------------------|--------------------|---|
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| Product<br>[short] data<br>sheet     | Production         | This document contains the product specification.                                     |

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